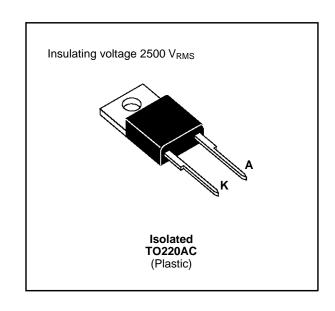


BYT 08PI-200 →400

FAST RECOVERY RECTIFIER DIODES

- VERY LOW REVERSE RECOVERY TIME
- VERY LOW SWITCHING LOSSES
- LOW NOISE TURN-OFF SWITCHING
- INSULATED: capacitance 7pF



SUITABLE APPLICATIONS

- FREE WHEELING DIODE IN CONVERTERS AND MOTOR CONTROL CIRCUITS
- RECTIFIER IN S.M.P.S.

ABSOLUTE MAXIMUM RATINGS (limiting values)

Symbol	Parameter	Value	Unit	
I _{FRM}	Repetive Peak Forward Current	t _p ≤ 10μs	130	Α
I _{F (RMS)}	RMS Forward Current	16	Α	
I _{F (AV)}	Average Forward Current	$T_c = 105^{\circ}C$ $\delta = 0.5$	8	А
I _{FSM}	Surge non Repetitive Forward Current	t _p = 10ms Sinusoidal	100	А
Р	Power Dissipation	T _c = 80°C	20	W
T _{stg} T _j	Storage and Junction Temperature Range		- 40 to +150	°C

Symbol	Parameter		BYT 08PI-		
Cymbol	Tarameter	200	300	400	Unit
V _{RRM}	Repetitive Peak Reverse Voltage	200	300	400	V
V _{RSM}	Non Repetitive Peak Reverse Voltage	220	330	440	V

THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
R _{th (j-c)}	Junction-case	3.5	°C/W

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ELECTRICAL CHARACTERISTICS

STATIC CHARACTERISTICS

Synbol	Test Conditions			Тур.	Max.	Unit
I _R	T _j = 25°C	$V_R = V_{RRM}$			15	μΑ
	T _j = 100°C				2.5	mA
V _F	T _j = 25°C	I _F = 8A			1.5	V
	T _j = 100°C				1.4	

RECOVERY CHARACTERISTICS

Symbol		Test Conditions					Max.	Unit
t _{rr}	T _j = 25°C	I _F = 1A	$di_F/dt = -15A/\mu s$	$V_R = 30V$			75	ns
		I _F = 0.5A	I _R = 1A	I _{rr} = 0.25A			35	

TURN-OFF SWITCHING CHARACTERISTICS (Without Series Inductance)

Symbol	Test Conditions			Тур.	Max.	Unit
t _{IRM}	di _F /dt = - 32A/μs	V _{CC} = 200 V I _F = 8A			75	ns
	$di_F/dt = -64A/\mu s$	$L_p \le 0.05 \mu H$ $T_j = 100$ °C See Figure 11		50		
I _{RM}	di _F /dt = - 32A/μs	Goo riguio ri			2.2	Α
	di _F /dt = - 64A/μs			2.8		

TURN-OFF OVERVOLTAGE COEFFICIENT (With Series Inductance)

Symbol	Test Condition s			Min.	Тур.	Max.	Unit
$C = \frac{V_{RP}}{V_{CC}}$	$T_j = 100^{\circ}C$ $di_F/dt = -8A/\mu s$	V_{CC} = 120V L_p = 9 μ H	$I_F = I_{F (AV)}$ See note See figure 12		3.3		

Note: Applicable to BYT 08 PI-400 only

To evaluate the conduction losses use the following equations:

$$V_F = 1.1 + 0.024 I_F$$
 $P = 1.1 \times I_{F(AV)} + 0.024 I_F^2_{(RMS)}$

Figure 1. Low frequency power losses versus average current

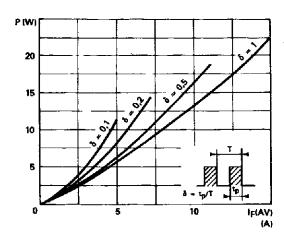


Figure 2. Peak current versus form factor $\,$

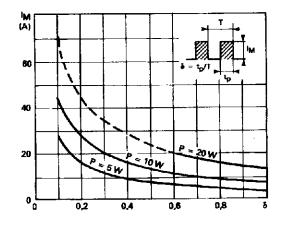


Figure 3. Non repetitive peak surge current versus overload duration

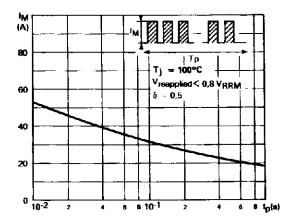


Figure 4. Thermal impedance versus pulse width

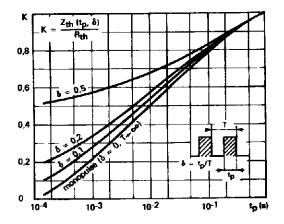


Figure 5. Voltage drop versus forward current

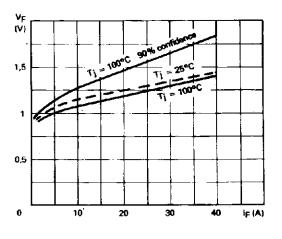


Figure 6. Recovery charge versus di_F/d_t-

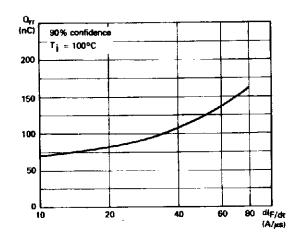


Figure 7. Recovery time versus di_F/d_{t-}

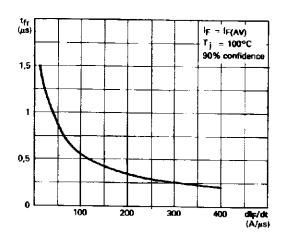


Figure 8. Peak reverse current versus di_F/d_t-

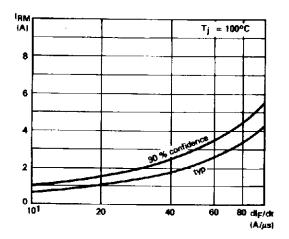


Figure 9. Peak forward voltage versus dir/dt-

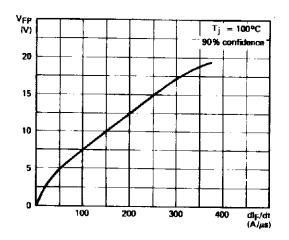


Figure 10. Dynamic parameters versus junction temperature.

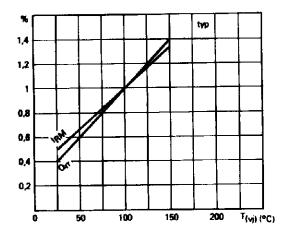


Figure 11. Turn-off switching characteristics (without series inductance).

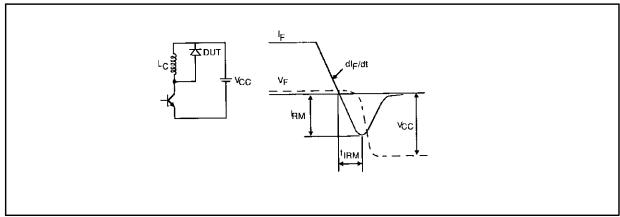
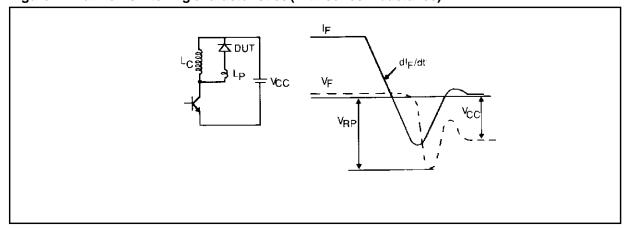
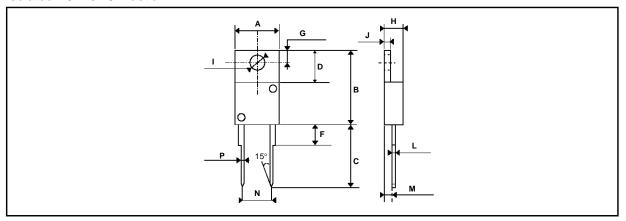


Figure 12. Turn-off switching characteristics (with series inductance).



PACKAGE MECHANICAL DATA

Isolated TO220AC Plastic



	DIMENSIONS					
REF.	Millimeters		Inc	hes		
	Min.	Max.	Min.	Max.		
Α	10.20	10.50	0.401	0.413		
В	14.23	15.87	0.560	0.625		
С	12.70	14.70	0.500	0.579		
D	5.85	6.85	0.230	0.270		
F		4.50		0.178		
G	2.54	3.00	0.100	0.119		
Н	4.48	4.82	0.176	0.190		
1	3.55	4.00	0.140	0.158		
J	1.15	1.39	0.045	0.055		
L	0.35	0.65	0.013	0.026		
М	2.10	2.70	0.082	0.107		
N	4.58	5.58	0.18	0.22		
Р	0.64	0.96	0.025	0.038		

Cooling method: by conduction (method C) Marking: type number Weight: 2.1g Recommended torque value: 80cm. N Maximum torque value: 100cm. N

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